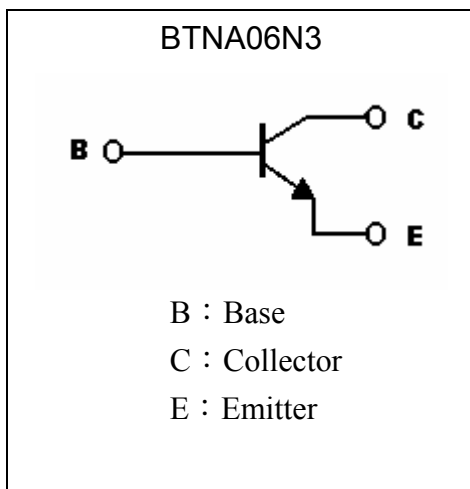
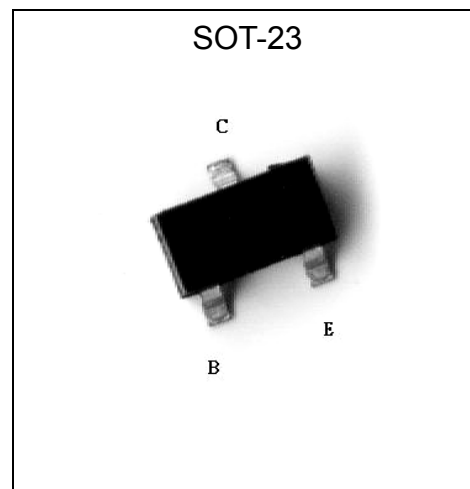


General Purpose NPN Epitaxial Planar Transistor

BTNA06N3

Description

- The BTNA06N3 is designed for use in general purpose amplification and switching application.
- High current , $I_C = 0.5A$
- Low $V_{CE(sat)}$, $V_{CE(sat)} = 0.25V(\text{typ.})$ at $I_C/I_B = 100mA/10mA$
- Complementary to BTPA56N3.
- Pb-free lead plating and halogen-free package

Symbol

Outline

Absolute Maximum Ratings ($T_a=25^\circ C$)

Parameter	Symbol	Limits	Unit
Collector-Base Voltage	V_{CBO}	150	V
Collector-Emitter Voltage	V_{CEO}	80	V
Emitter-Base Voltage	V_{EBO}	7	V
Collector Current	I_C	500	mA
Power Dissipation	P_D	225	mW
Junction Temperature	T_j	150	$^\circ C$
Storage Temperature	T_{stg}	-55~+150	$^\circ C$

**Characteristics (Ta=25°C)**

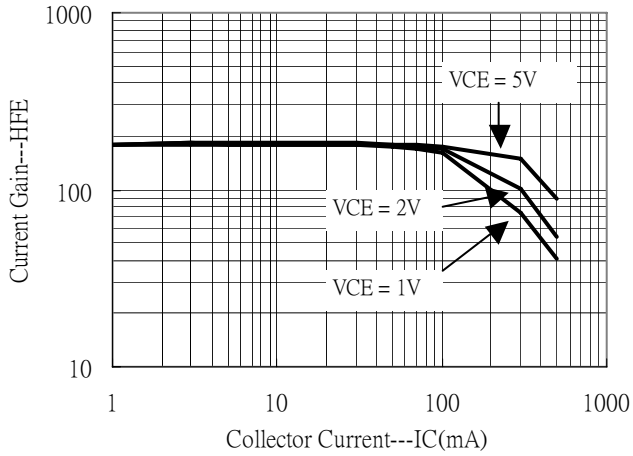
Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BV_{CBO}	150	-	-	V	$I_C=100\mu A$
BV_{CEO}	80	-	-	V	$I_C=1mA$
BV_{EBO}	7	-	-	V	$I_E=100\mu A$
I_{CBO}	-	-	100	nA	$V_{CB}=120V$
I_{CES}	-	-	100	nA	$V_{CE}=60V$
I_{EBO}	-	-	100	nA	$V_{EB}=7V$
$*V_{CE(sat)}$	-	-	0.25	V	$I_C=100mA, I_B=10mA$
$*V_{BE(on)}$	-	-	1.2	V	$V_{CE}=1V, I_C=100mA$
$*h_{FE1}$	100	-	-	-	$V_{CE}=1V, I_C=10mA$
$*h_{FE2}$	100	-	-	-	$V_{CE}=1V, I_C=100mA$
f_T	100	-	-	MHz	$V_{CE}=2V, I_C=10mA, f=100MHz$

*Pulse Test: Pulse Width $\leq 380\mu s$, Duty Cycle $\leq 2\%$ **Ordering Information**

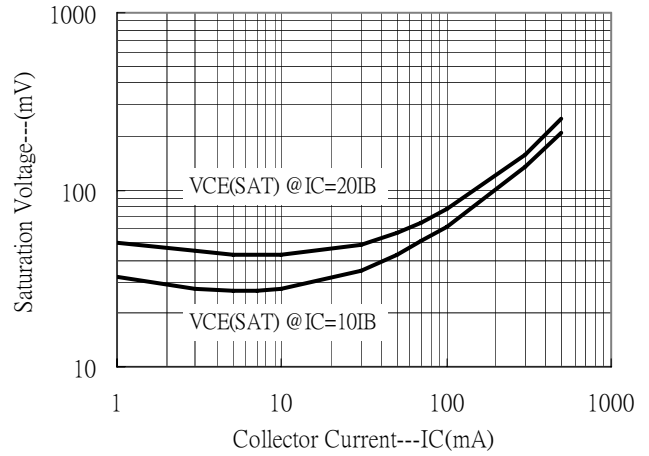
Device	Package	Shipping
BTNA06N3-0-T1-G	SOT-23 (Pb-free lead plating and halogen-free package)	3000 pcs / Tape & Reel

Characteristic Curves

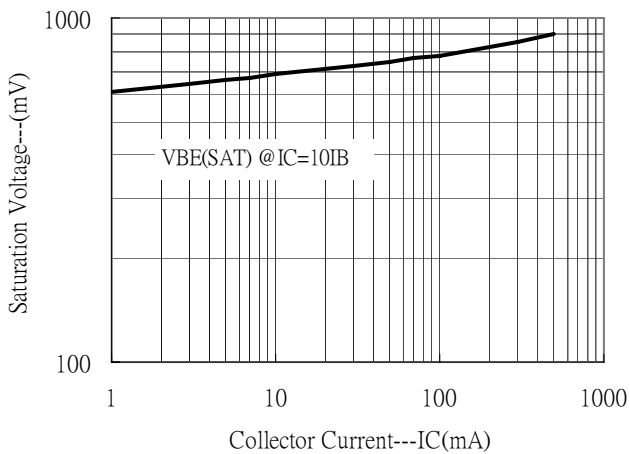
Current Gain vs Collector Current



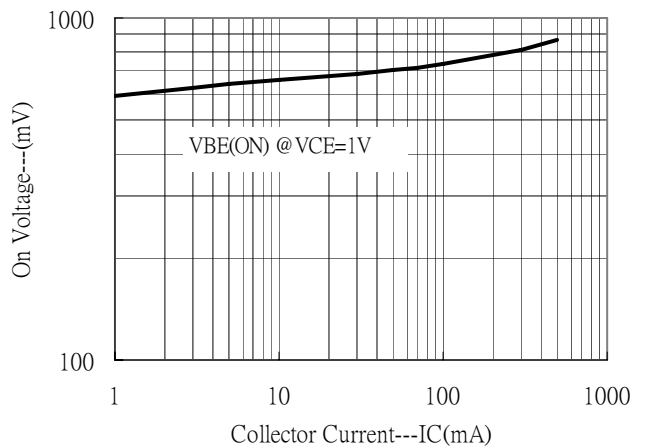
Saturation Voltage vs Collector Current



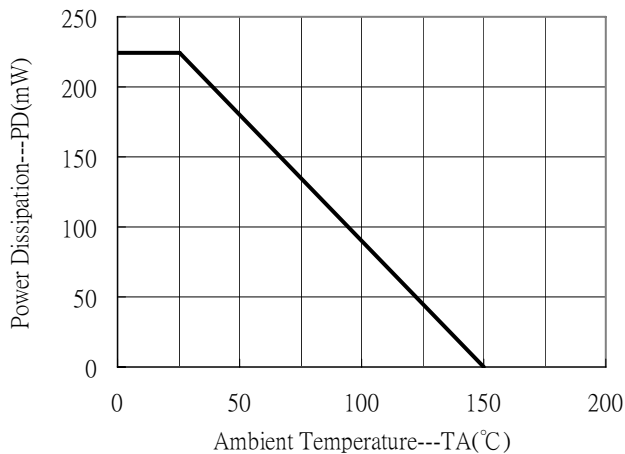
Saturation Voltage vs Collector Current



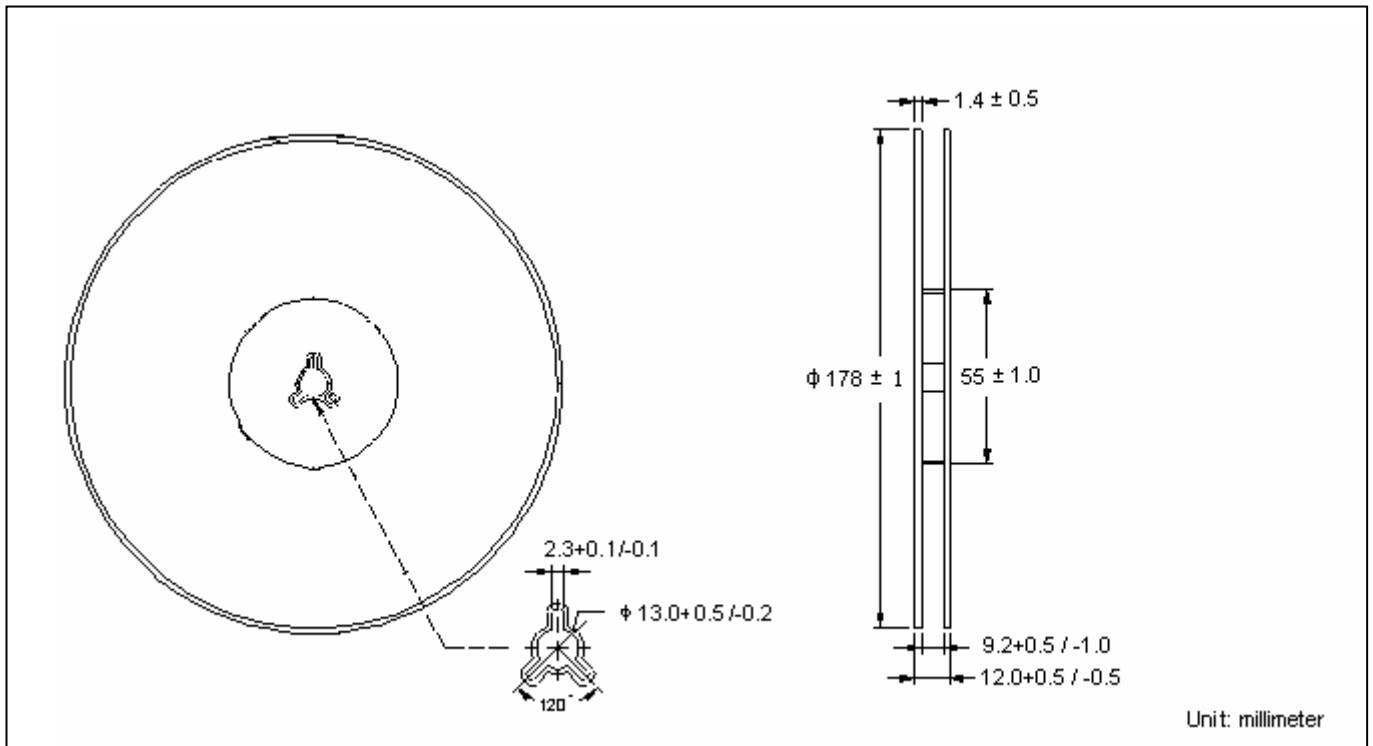
On Voltage vs Collector Current



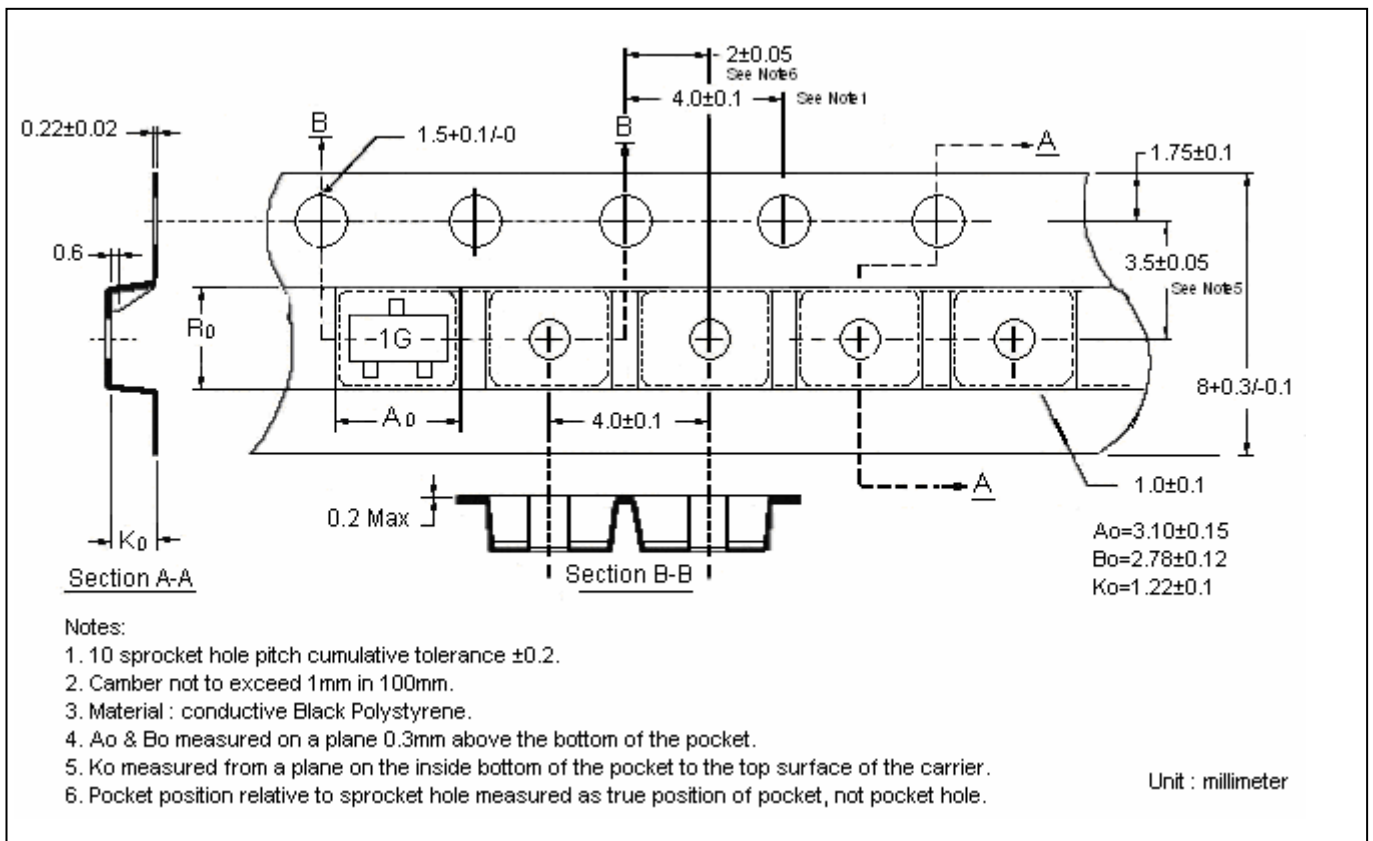
Power Derating Curve



Reel Dimension



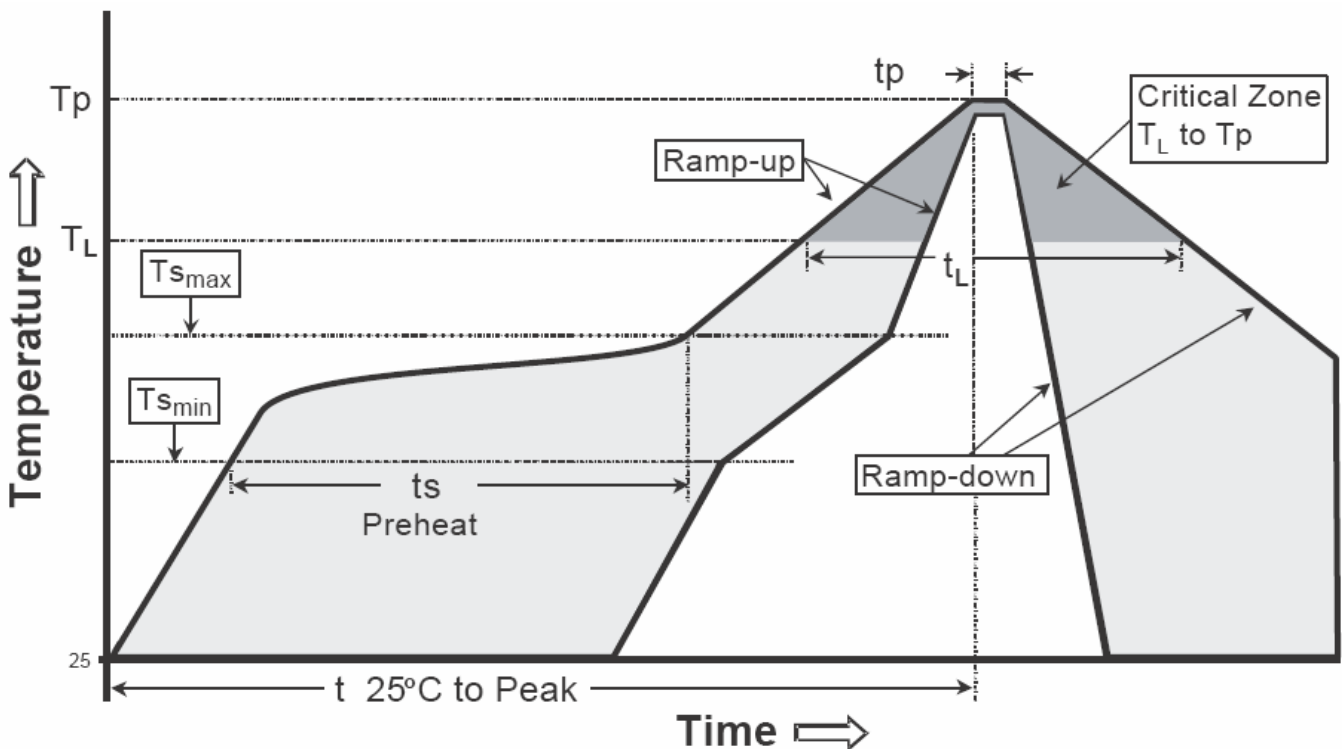
Carrier Tape Dimension



Recommended wave soldering condition

Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

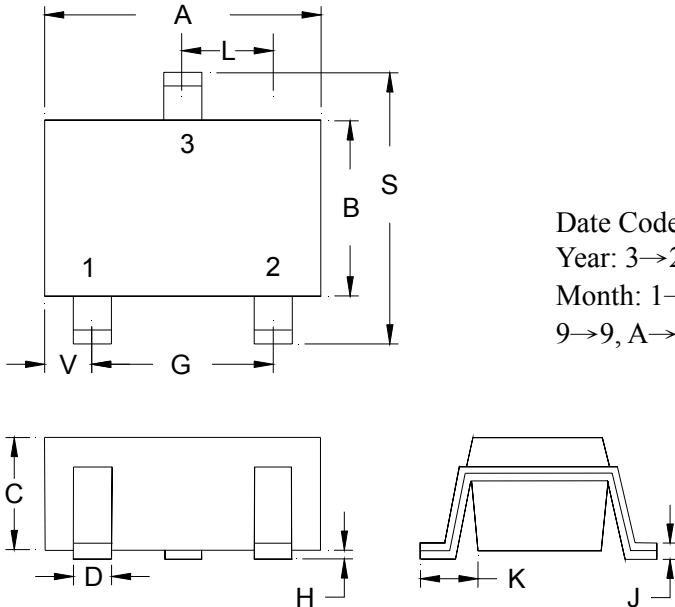
Recommended temperature profile for IR reflow



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (Ts_max to Tp)	3°C/second max.	3°C/second max.
Preheat		
-Temperature Min(Ts_min)	100°C	150°C
-Temperature Max(Ts_max)	150°C	200°C
-Time(ts_min to ts_max)	60-120 seconds	60-180 seconds
Time maintained above:		
-Temperature (T_L)	183°C	217°C
- Time (t_L)	60-150 seconds	60-150 seconds
Peak Temperature(T_P)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

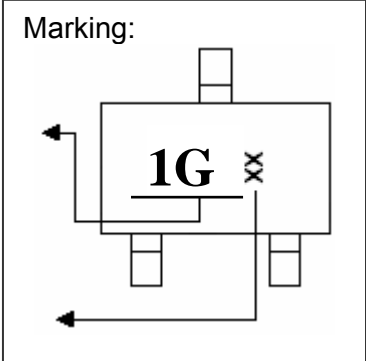
Note : All temperatures refer to topside of the package, measured on the package body surface.

SOT-23 Dimension



The diagram shows three views of the SOT-23 package: a top view with dimensions A, L, B, S, 1, 2, 3, V, and G; a side view with dimensions C, D, and H; and a perspective view with dimensions K and J. The top view labels 1, 2, and 3 correspond to Pin 1, Base, and Collector respectively.

Marking:



The marking diagram shows a rectangular package with three leads. The top lead is labeled '1G' with a cross symbol to its right. Arrows indicate the lead connections.

Product Code

Date Code: Year+Month
 Year: 3→2003, 4→2004
 Month: 1→1, 2→2, . . .
 9→9, A→10, B→11, C→12

3-Lead SOT-23 Plastic Surface Mounted Package
 CYStek Package Code: N3

Style : Pin 1.Base 2.Emitter 3.Collector

*:Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.1102	0.1204	2.80	3.04	J	0.0034	0.0070	0.085	0.177
B	0.0472	0.0630	1.20	1.60	K	0.0128	0.0266	0.32	0.67
C	0.0335	0.0512	0.89	1.30	L	0.0335	0.0453	0.85	1.15
D	0.0118	0.0197	0.30	0.50	S	0.0830	0.1083	2.10	2.75
G	0.0669	0.0910	1.70	2.30	V	0.0098	0.0256	0.25	0.65
H	0.0005	0.0040	0.013	0.10					

Notes : 1.Controlling dimension : millimeters.
 2.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.
 3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material :

- Lead : Pure tin plated.
- Mold Compound : Epoxy resin family, flammability solid burning class:UL94V-0.

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